AS A BELOW NAMED INVENTOR, I hereby declare that:

My residence, post office address and citizenship are as stated next to my name.

I believe that I am the original, first and sole (if only one name is listed below), or an original, first and joint inventor (if plural names are listed below), of the subject matter which is claimed and for which a patent is sought on the invention entitled:

TITLE: METHOD OF FORMING AN UNDERLAYER OF A BI-LAYER RESIST FILM AND METHOD OF FABRICATING A SEMICONDUCTOR DEVICE USING THE SAME

USING THE SAN	HOD OF FABRICATING A SEMICO ME	MOUCION DEVICE
the specification of which either is	attached hereto or indicates an attorney	docket no. 8028-42 (SPX200304-0017US)
or:		
was filed in the U.S. Patent & Tra	ademark Office on and	assigned Serial No,
and (if applicable) was amended	on	,
as amended by any amendment ref patentability and to the examination of hereby claim foreign priority benefits inventor's certificate, or §365(a) of ar	Ferred to above. I acknowledge the duty of this application in accordance with Title 3 nunder Title 35, U.S. Code §119(a)-(d) or §3 ny PCT international application which designtified below any foreign applications for particular to the particular of the particula	re-identified specification, including the claims, to disclose information which is material to 7 of the Code of Federal Regulations §1.56. I 65(b) of any foreign application(s) for patent or mated at least one country other than the United tent or inventor's certificate having a filing date
Priority Claimed:		
2003-40773	KOREA	23 June 2003
(Application Number)	(Country)	(Day/Month/Year filed)
(Application Number)	(Country)	(Day/Month/Year filed)
States provisional application(s), or §	365(c) of any PCT International application	States application(s), or §119(e) of any United designating the United States, listed below and, disclosed in the prior United States or PCT

I hereby claim the benefit under Title 35, U.S. Code, §120 of any United States application(s), or §119(e) of any United States provisional application(s), or §365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application(s) in the manner provided by the first paragraph of Title 35, U.S. Code, §112, I acknowledge the duty to disclose information material to patentability as defined in Title 37, The Code of Federal Regulations, §1.56(a) which became available between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial Number) (Filing Date) (STATUS: patented, pending, abandoned)

I hereby appoint the following attorneys: FRANK CHAU, Reg. No. 34,136; FRANK V. DeROSA, Reg. No. 43,584; NATHANIEL T. WALLACE, Reg. No. 48,909; ERIC M. PARHAM, Reg. No. 45,747; THOMAS W. McNALLY, Reg. No. 48,609; MICHAEL F. MORANO, Reg. No. 44,952; KOON H. WONG, Reg. No. 48,459; BENJAMIN M. HALPERN, Reg. No. 46,494; and RICHARD D. RATCHFORD JR., Reg. No. 53,865; and each of them of F. CHAU & ASSOCIATES, LLC, 1900 Hempstead Turnpike, Suite 501, East Meadow, New York 11554 to prosecute this application and to transact all business in the U.S. Patent and Trademark Office connected therewith and with any divisional, continuation, continuation-in-part, reissue or re-examination application, with full power of appointment and with full power to substitute an associate attorney or agent, and to receive all patents which may issue thereon, and request that all correspondence be addressed to:

Frank Chau, Esq. F. CHAU & ASSOCIATES, LLC 1900 Hempstead Tumpike, Suite 501 East Meadow, New York 11554 Area Code: 516-357-0091 I HEREBY DECLARE that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under '1001 of Title 18 U.S. Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

FULL NAME OF FIRST OR SOLE INVENTOR: HYUN-WOO KIM		Citizenship: KOREA
Inventor=s signature: HYUW - C	200 KIM	Date: Feb 10, 1008
	922-1004, Samsung Apt., Yeongtong-dong, Paldal-gu Suwon-city, Gyeonggi-do, Republic of Korea	
· :		
FULL NAME OF SECOND INVENTO	Citizenship: KOREA	
Inventor=s signature:	in Hong	Date: 10 10 100 9
Residence & Post Office Address:	103-103 Daechang Apt., 359, Byeongjeom-ri, Taean-eul Hwanscong-gun, Gyeonggi-do, Republic of Korea	, /
FULL NAME OF THIRD INVENTOR	: MYOUNG-HO JUNG	Citizenship:
Inventor=s signature: MYOUNG-H	O JUNG	Date: Feb. 10, 2004
Residence & Post Office Address:	7-1, Nongseo-ri, Kiheung-eub, Yongin-city Gyeonggi-do, Republic of Korea	
FULL NAME OF FOURTH INVENTOR: <u>SANG-GYUN WOO</u>		_ Citizenship: KOREA
Inventor=s signature:SANG-	GYUN WOO	Date: Teb. 10, 2004
Residence & Post Office Address:	523-1704, Samsung Scha Apt., Pungdeokcheon-ri, Suji Yongin-city. Gyeonggi-do, Republic of Korea	-eub